

TOSHIBA Field Effect Transistor Silicon N Channel Dual Gate MOS Type

# 3SK226

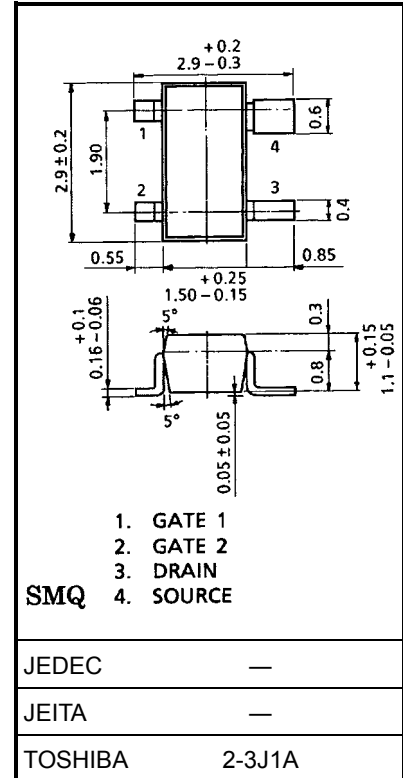
TV Tuner, VHF RF Amplifier Applications  
FM Tuner Applications

Unit: mm

- Superior cross modulation performance.
- Low reverse transfer capacitance:  $C_{RSS} = 0.015$  pF (typ.)
- Low noise figure: NF = 1.1dB (typ.)

### Maximum Ratings (Ta = 25°C)

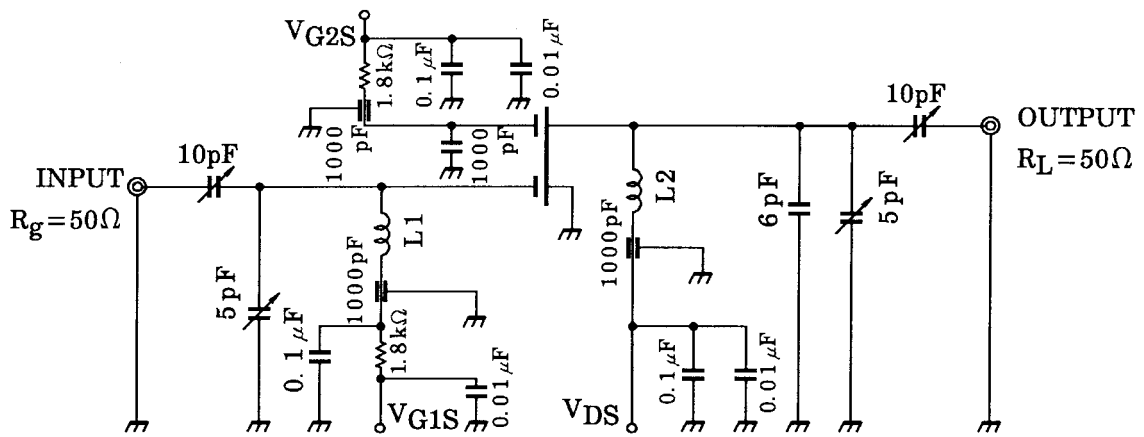
Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DS}$	13.5	V
Gate 1-source voltage	$V_{G1S}$	$\pm 8$	V
Gate 2-source voltage	$V_{G2S}$	$\pm 8$	V
Drain current	$I_D$	30	mA
Drain power dissipation	$P_D$	150	mW
Channel temperature	$T_{ch}$	125	°C
Storage temperature range	$T_{stg}$	-55~125	°C



Weight: 0.013 g (typ.)

### Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate 1 leakage current	$I_{G1SS}$	$V_{DS} = 0, V_{G1S} = \pm 6$ V, $V_{G2S} = 0$	—	—	$\pm 50$	nA
Gate 2 leakage current	$I_{G2SS}$	$V_{DS} = 0, V_{G1S} = 0, V_{G2S} = \pm 6$ V	—	—	$\pm 50$	nA
Drain-source voltage	$V_{(BR)DSX}$	$V_{G1S} = -4$ V, $V_{G2S} = -4$ V, $I_D = 100$ $\mu$ A	13.5	—	—	V
Drain current	$I_{DSS}$	$V_{DS} = 6$ V, $V_{G1S} = 0, V_{G2S} = 4.5$ V	0	—	0.1	mA
Gate 1-source cut-off voltage	$V_{G1S(OFF)}$	$V_{DS} = 6$ V, $V_{G2S} = 4.5$ V, $I_D = 100$ $\mu$ A	0	—	1.0	V
Gate 2-source cut-off voltage	$V_{G2S(OFF)}$	$V_{DS} = 6$ V, $V_{G1S} = 4$ V, $I_D = 100$ $\mu$ A	0.5	1.0	1.5	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 6$ V, $V_{G2S} = 4.5$ V, $I_D = 10$ mA, $f = 1$ kHz	—	13	—	mS
Input capacitance	$C_{iss}$	$V_{DS} = 6$ V, $V_{G2S} = 4.5$ V, $I_D = 10$ mA, $f = 1$ MHz	2.1	2.7	3.3	pF
Reverse transfer capacitance	$C_{rss}$		—	0.015	0.03	pF
Power gain	$G_{ps}$	$V_{DS} = 6$ V, $V_{G2S} = 4.5$ V, $I_D = 10$ mA, $f = 200$ MHz (Figure 1)	23	27	—	dB
Noise figure	NF		—	1.1	2.2	dB

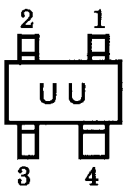


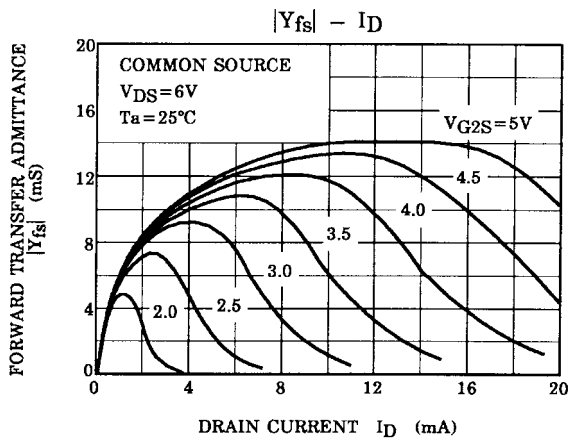
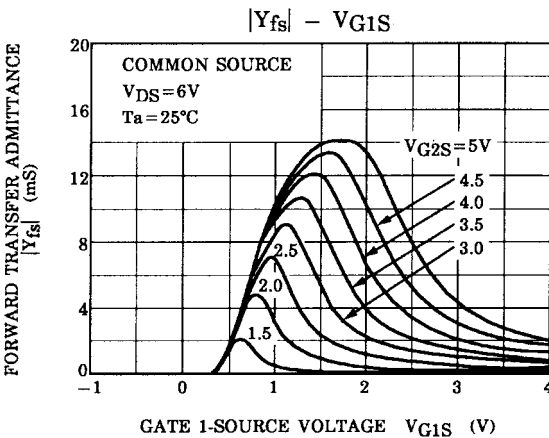
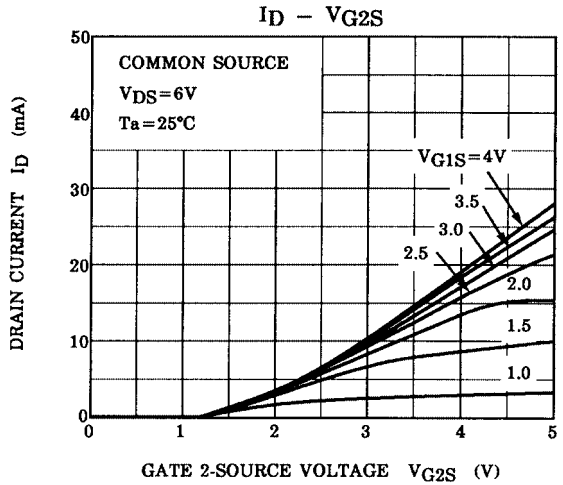
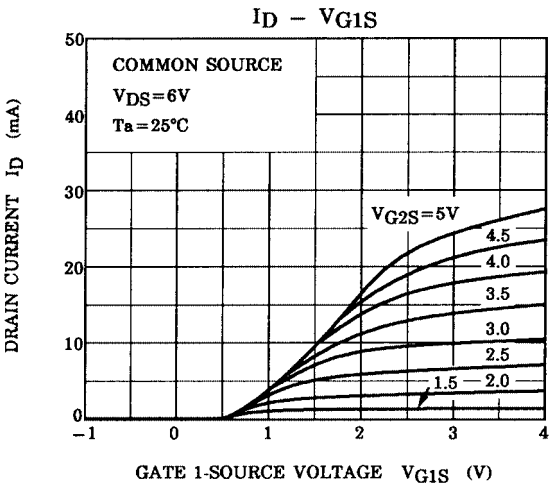
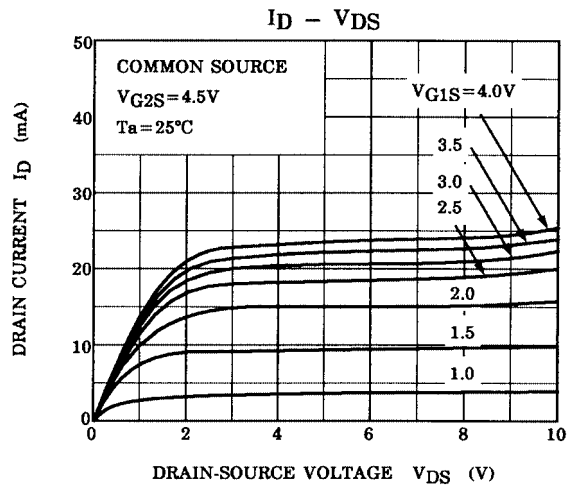
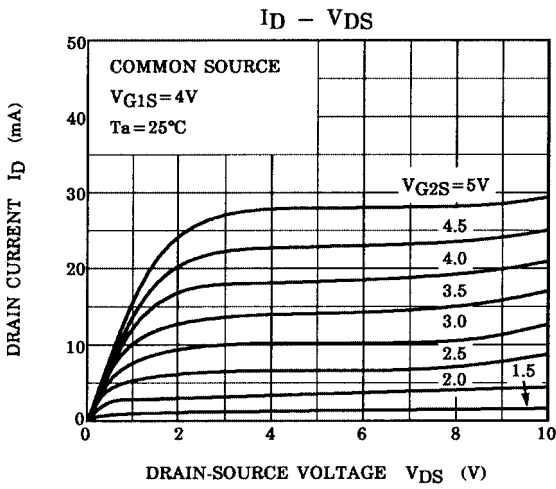
L1: 1 mmφ Ag plated copper wire, 2 turns, 8 mm ID

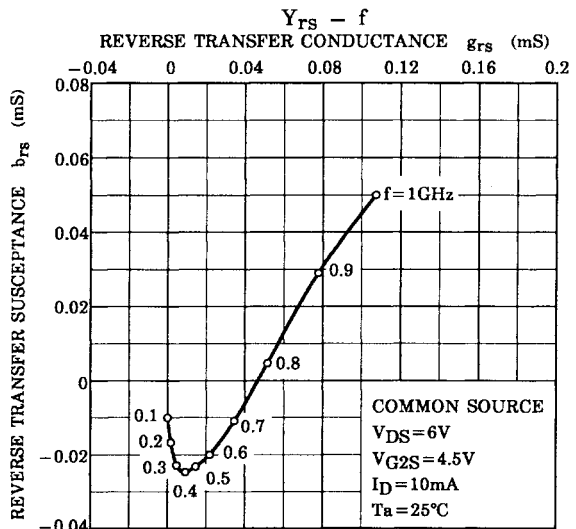
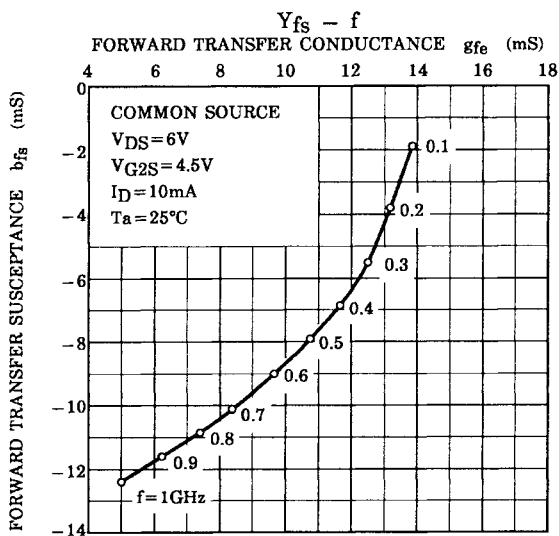
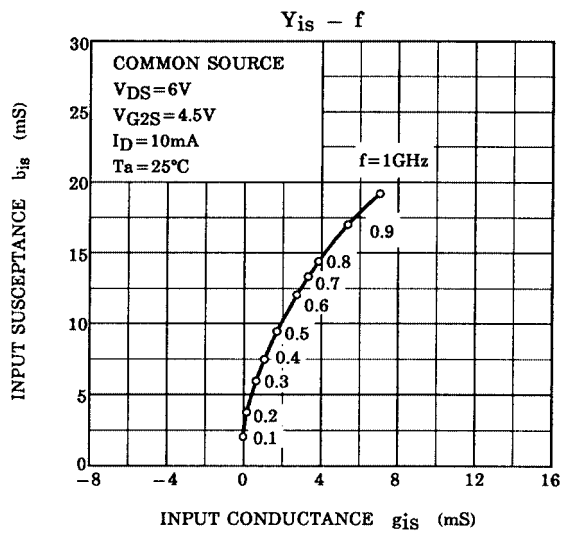
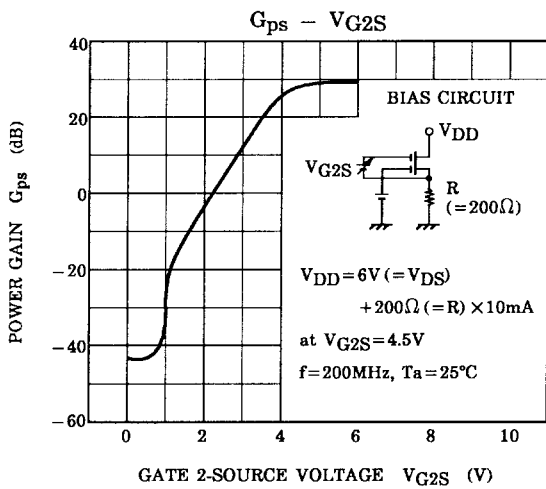
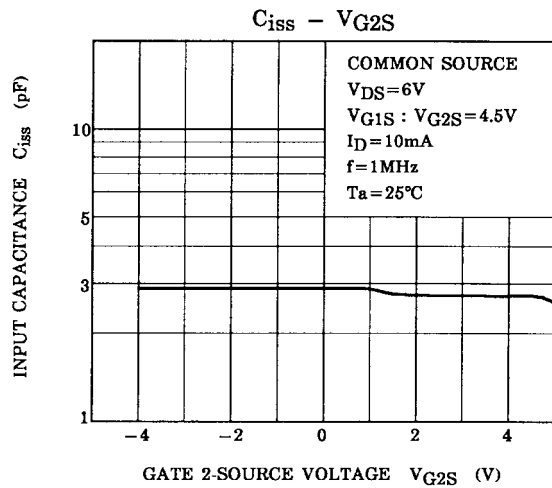
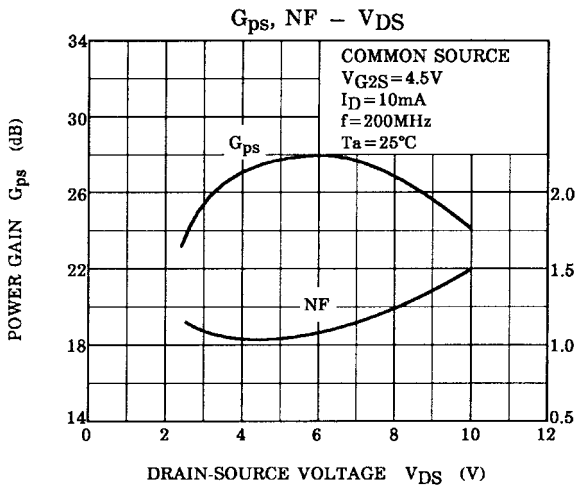
L2: 1 mmφ Ag plated copper wire, 2.5 turns, 8 mm ID

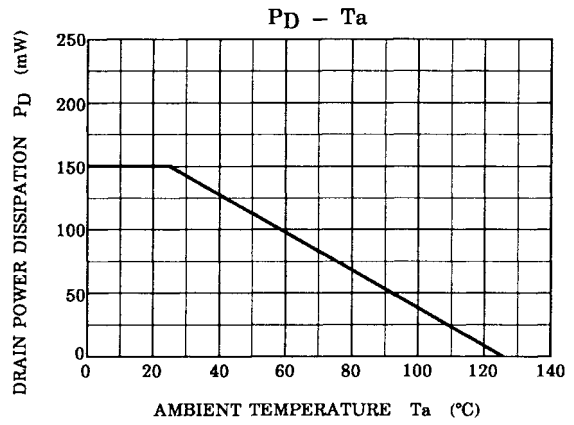
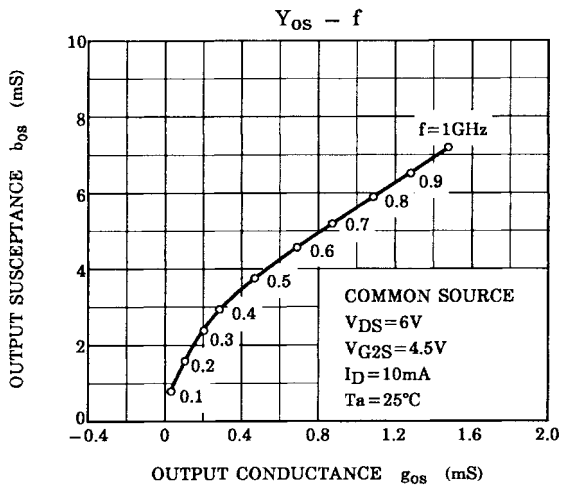
**Figure 1 200 MHz, G<sub>ps</sub> NF Test Circuit**

**Marking**









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